

SN75ALS193 四路差分线路接收器

1 特性

- 符合或超出 ANSI 标准 EIA/TIA-422-B 和 EIA/TIA-423-A 以及 ITU 建议 V.10 和 V.11 的要求
- 适用于嘈杂环境中长总线上的多点总线传输
- 三态输出
- 共模输入电压范围：-7V 至 7V
- 输入灵敏度：±200mV
- 输入迟滞：120mV (典型值)
- 高输入阻抗：12kΩ (最小值)
- 由 5V 单电源供电
- 低电源电流要求 (最高 35mA)
- 较 AM26LS32A 版本改善了速度和功耗

2 应用

- 电机驱动器
- 工厂自动化和控制

3 说明

SN75ALS193 是一款采用高级低功耗肖特基技术、具有三态输出的单片四路线路接收器。该技术在 bar 设计、加工生产和晶圆制造方面实现了综合改进，因此，

与其他设计相比，显著降低了功耗要求并允许高得多的数据吞吐量。此器件符合 ANSI 标准 EIA/TIA-422-B 和 EIA/TIA-423-A 以及 ITU 建议 V.10 和 V.11 的规范要求。它具有三态输出，允许直接连接到总线式系统，并且采用失效防护设计，可确保在输入处于开路状态时输出始终处于高电平状态。

该器件经优化，能够以高达 20 兆位/秒的速率实现平衡多点总线传输。该输入具有高输入阻抗、用于提高抗噪性的输入迟滞、以及在 -7V 至 7V 共模输入电压范围内 ±200mV 的输入灵敏度。该器件还具有四个通道所共用的高电平有效和低电平有效使能功能。SN75ALS193 与 'ALS192 四路差分线路驱动器配合使用时，可实现卓越性能。

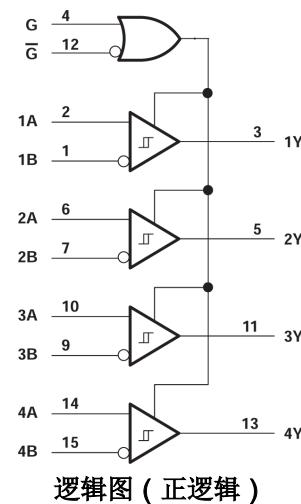
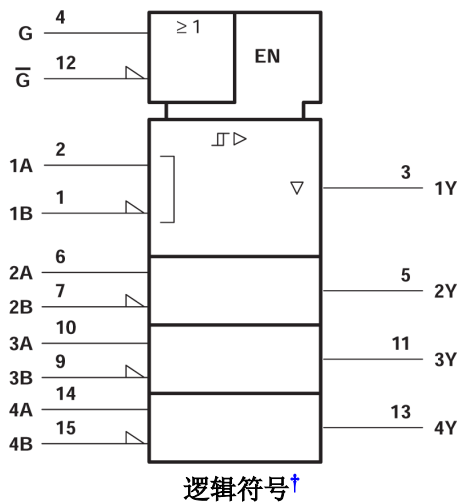
SN75ALS193 的额定工作温度范围为 0°C 至 70°C。

封装信息

器件型号	封装 ⁽¹⁾	封装尺寸 ⁽²⁾
SN75ALS193	N (PDIP, 16)	19.3mm × 9.4mm
	D (SOIC, 16)	9.9mm × 6mm

(1) 如需更多信息，请参阅节 10。

(2) 封装尺寸 (长 × 宽) 为标称值，并包括引脚 (如适用)。



[†] 此符号符合 ANSI/IEEE 标准 91-1984 和 IEC 出版物 617-12。



Table of Contents

1 特性	1	6 Parameter Measurement Information	10
2 应用	1	7 Detailed Description	12
3 说明	1	7.1 Device Functional Modes.....	12
4 Pin Configuration and Functions	3	8 Device and Documentation Support	13
5 Specifications	4	8.1 接收文档更新通知.....	13
5.1 Absolute Maximum Ratings.....	4	8.2 支持资源.....	13
5.2 Dissipation Rating.....	4	8.3 Trademarks.....	13
5.3 Recommended Operating Conditions.....	4	8.4 静电放电警告.....	13
5.4 Thermal Information.....	4	8.5 术语表.....	13
5.5 Electrical Characteristics.....	5	9 Revision History	13
5.6 Switching Characteristics.....	5	10 Mechanical, Packaging, and Orderable	
5.7 Typical Characteristics.....	6	Information	13

4 Pin Configuration and Functions

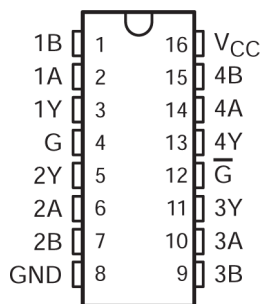


图 4-1. D or N Package (Top View)

表 4-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
1B	1	I	Channel 1 Differential Receiver Inverting Input
1A	2	I	Channel 1 Differential Receiver Non-Inverting Input
1Y	3	O	Channel 1 Single Ended Output
G	4	I	Active High Enable
2Y	5	O	Channel 2 Single Ended Output
2A	6	I	Channel 2 Differential Receiver Non-Inverting Input
2B	7	I	Channel 2 Differential Receiver Inverting Input
GND	8	GND	Device GND
3B	9	I	Channel 3 Differential Receiver Inverting Input
3A	10	I	Channel 3 Differential Receiver Non-Inverting Input
3Y	11	O	Channel 3 Single Ended Output
$\bar{G}$	12	I	Active Low Enable
4Y	13	O	Channel 4 Single Ended Output
4A	14	I	Channel 4 Differential Receiver Non-Inverting Input
4B	15	I	Channel 4 Differential Receiver Inverting Input
V _{CC}	16	PWR	Device VCC (4.75V to 5.25V)

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V_{CC}	Supply voltage, see ⁽²⁾		7	V
V_I	Input voltage, A or B		± 15	V
V_{ID}	Differential input voltage, see ⁽³⁾		± 15	V
V_I	Enable input voltage		7	V
I_{OL}	Low-level output current		50	mA
	Continuous total dissipation	See Dissipation Rating table		
T_A	Operating free-air temperature range	0	70	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds		300	°C
T_{stg}	Storage temperature range	- 65	150	°C

- (1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential input voltage, are with respect to network ground terminal.
- (3) Differential-input voltage is measured at the noninverting input with respect to the corresponding inverting input.

5.2 Dissipation Rating

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING
N	1150 mW	9.2 mW/°C	736 mW

5.3 Recommended Operating Conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}	4.75	5	5.25	V
Common-mode input voltage, V_{IC}			± 7	V
Differential input voltage, V_{ID}			± 12	V
High-level input voltage, V_{IH}	2			V
Low-level input voltage, V_{IL}			0.8	V
High-level output current, I_{OH}			- 400	μA
Low-level output current, I_{OL}			16	mA
Operating free-air temperature, T_A	0	70		°C

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		SN75ALS193		UNIT
		N (PDIP)	D (SOIC)	
		16 Pins	16 Pins	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	60.6	84.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	48.1	43.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	40.6	43.2	°C/W
ψ_{JT}	Junction-to-top characterization parameter	27.5	10.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	40.3	42.8	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

5.5 Electrical Characteristics

over recommended range of common-mode input voltage, supply voltage, and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	TYP ⁽²⁾	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage					200	mV
V _{IT-}	Negative-going input threshold voltage			- 200 ⁽³⁾			mV
V _{hys}	Hysteresis voltage (V _{IT+} - V _{IT-})				120		mV
V _{IK}	Enable-input clamp voltage	V _{CC} = MIN,	I _I = - 18 mA			- 1.5	V
V _{OH}	High-level output voltage	V _{CC} = MIN, I _{OH} = - 400 μ A,	V _{ID} = 200 mV, See Figure 1	2.5	1.6		V
V _{OL}	Low-level output voltage	V _{CC} = MIN, V _{ID} = - 200 mV, See Figure 1	I _{OL} = 8 mA			0.45	V
			I _{OL} = 16 mA			0.5	
I _{OZ}	High-impedance-state output current	V _{CC} = MAX	V _O = 2.4 V			20	μ A
			V _O = 0.4 V			- 20	
I _I	Line input current	Other input at 0, See ⁽⁴⁾	V _{CC} = MIN, V _I = 15 V		0.7	1.2	mA
			V _{CC} = MIN, V _I = - 15 V		- 1.0	- 1.7	
I _{IH}	High-level enable-input current	V _{CC} = MAX	V _{IH} = 2.7 V			20	μ A
			V _{IH} = MAX			100	
I _{IL}	Low-level enable-input current	V _{CC} = MAX,	V _{IL} = 0.4 V			- 100	μ A
	Input resistance			12	18		k Ω
I _{OS}	Short-circuit output current	V _{CC} = MAX, V _O = 0,	V _{ID} = 3 V, See ⁽⁵⁾	- 15	- 78	- 130	mA
I _{CC}	Supply current	V _{CC} = MAX,	Outputs disabled		22	35	mA

- (1) For conditions shown as MIN or MAX, use the appropriate values specified under recommended operating conditions.
- (2) All typical values are at V_{CC} = 5 V, T_A = 25°C.
- (3) The algebraic convention, in which the less positive limit is designated minimum, is used in this data sheet for threshold voltage levels only.
- (4) Refer to ANSI Standard EIA/TIA-422-B and EIA/TIA-423-A for exact conditions.
- (5) Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.

5.6 Switching Characteristics

V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high-level output	V _{ID} = - 2.5 V to 2.5 V			15	22	ns
t _{PHL}	Propagation delay time, high-to-low-level output	C _L = 15 pF	See 图 6-1		15	22	
t _{PZH}	Output enable time to high level	C _L = 15 pF	See 图 6-2		13	25	
					11	25	
t _{PHZ}	Output disable time from high level	C _L = 5 pF	See 图 6-2		13	25	
					15	22	

5.7 Typical Characteristics

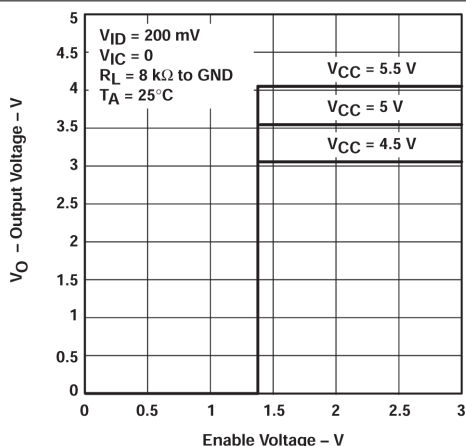


图 5-1. Output Voltage vs Enable Voltage

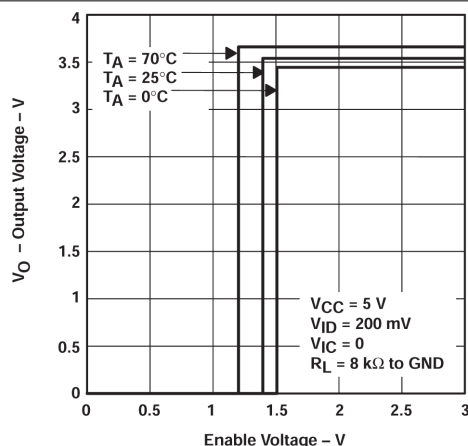


图 5-2. Output Voltage vs Enable Voltage

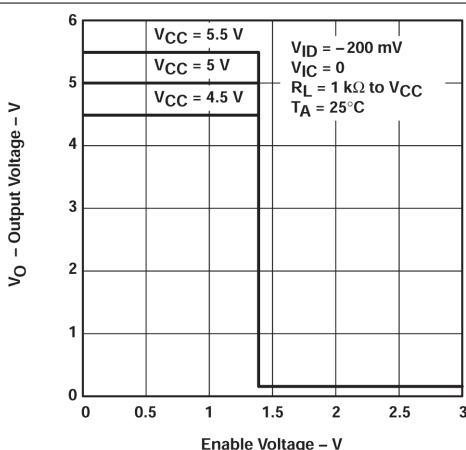


图 5-3. Output Voltage vs Enable Voltage

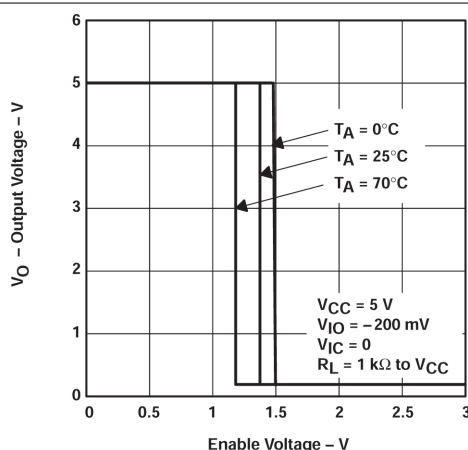


图 5-4. Output Voltage vs Enable Voltage

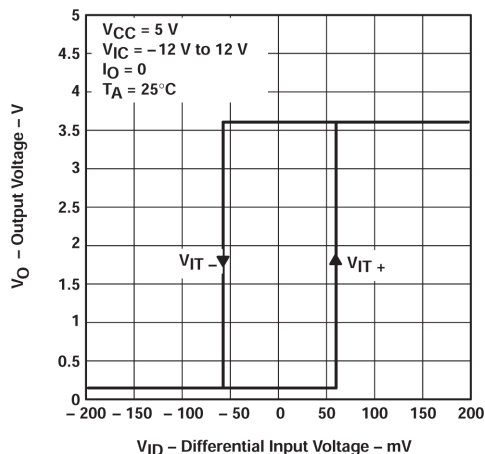


图 5-5. Output Voltage vs Differential Input Voltage

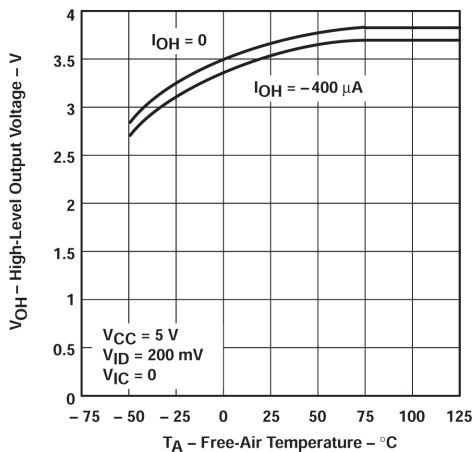


图 5-6. High-level Output Voltage vs Free-air Temperature

5.7 Typical Characteristics (continued)

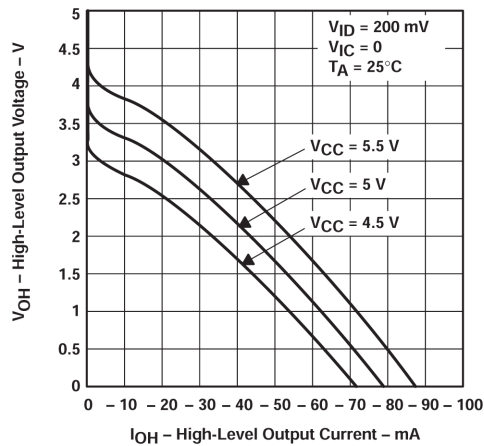


图 5-7. High-level Output Voltage vs High-level Output Current

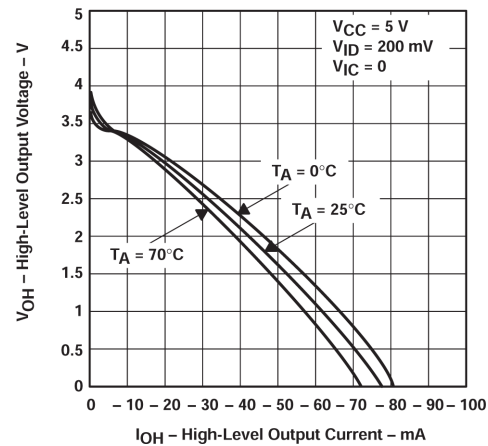


图 5-8. High-level Output Voltage vs High-level Output Current

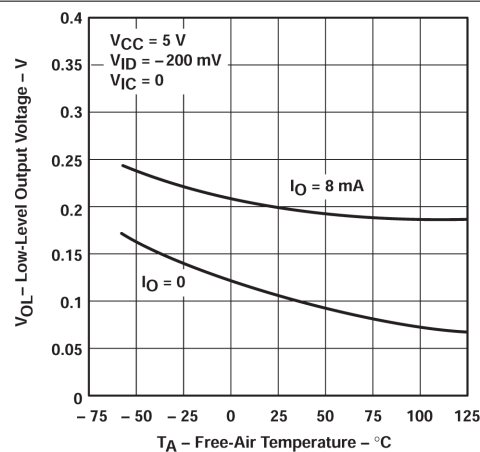


图 5-9. Low-level Output Voltage vs Free-air Temperature

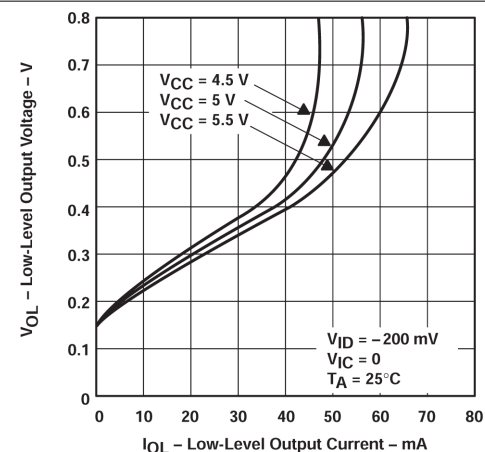


图 5-10. Low-level Output Voltage vs Low-level Output Current

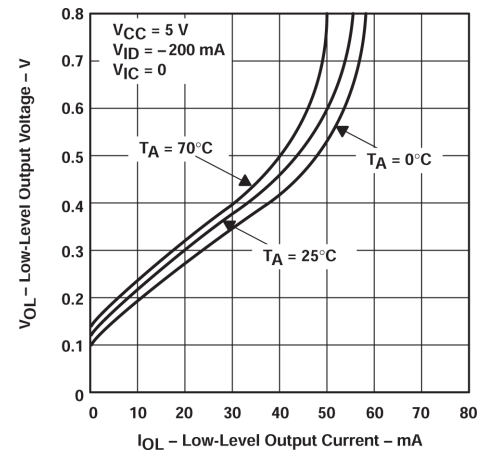


图 5-11. Low-level Output Voltage vs Low-level Output Current

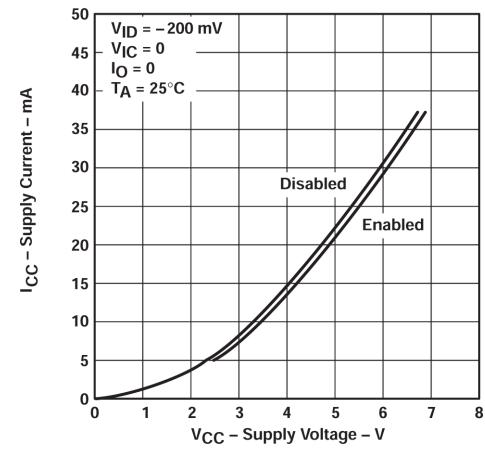


图 5-12. Supply Current vs Supply Voltage

5.7 Typical Characteristics (continued)

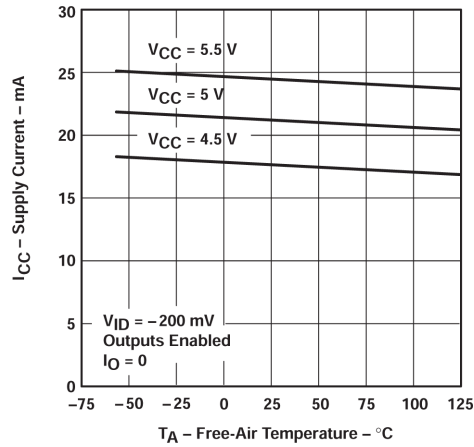


图 5-13. Supply Current vs Free-air Temperature

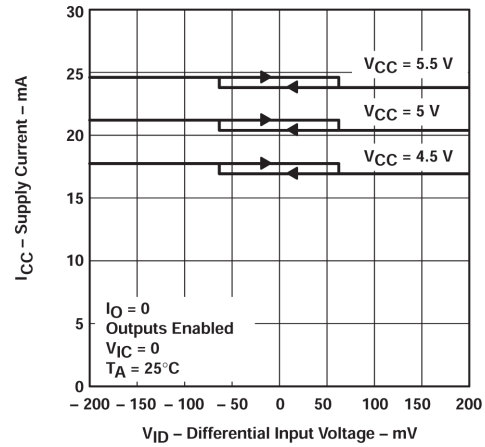


图 5-14. Supply Current vs Differential Input Voltage

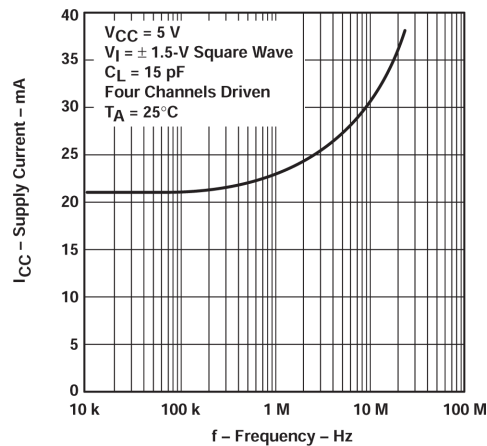


图 5-15. Supply Current vs Frequency

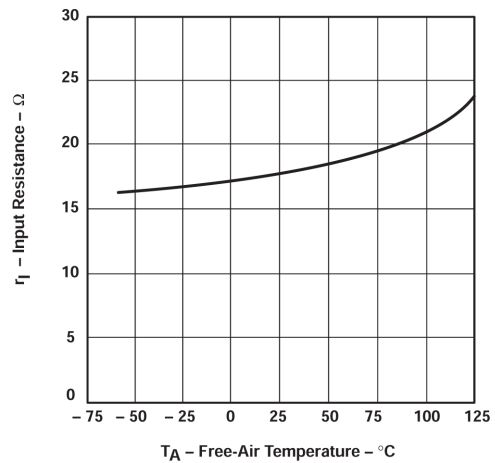


图 5-16. Input Resistance vs Free-air Temperature

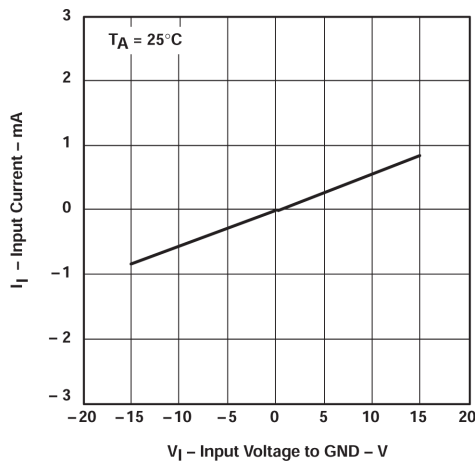


图 5-17. Input Current vs Input Voltage to GND

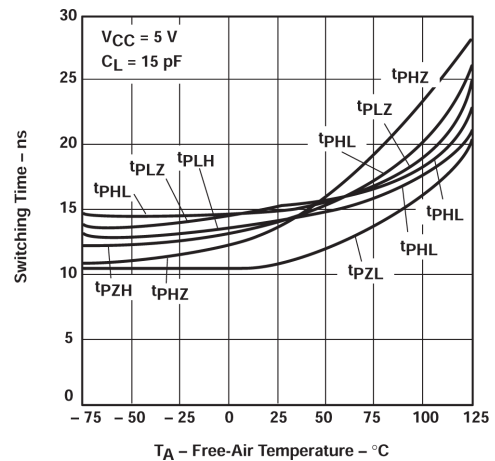


图 5-18. Switching Time vs Free-air Temperature

5.7 Typical Characteristics (continued)

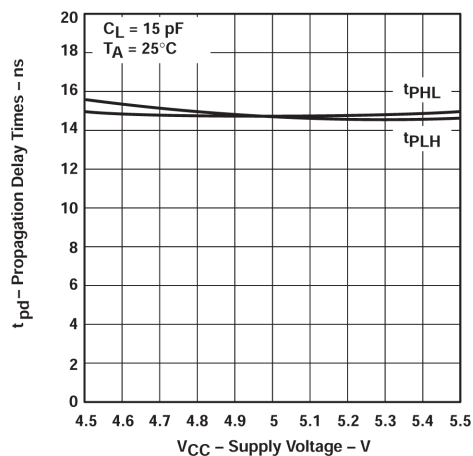


图 5-19. Propagation Delay Time vs Supply Voltage

6 Parameter Measurement Information

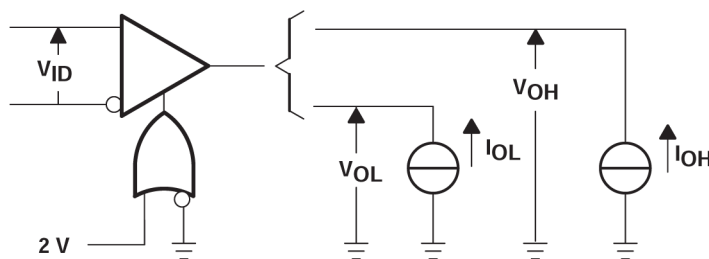
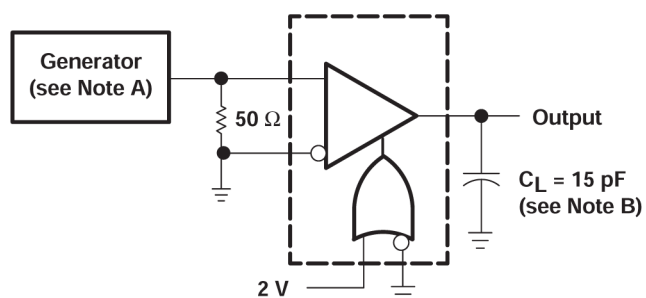
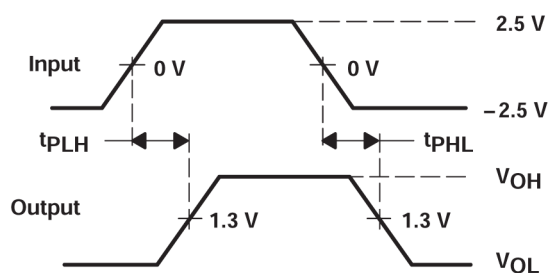


图 6-1. V_{OH} , V_{OL}



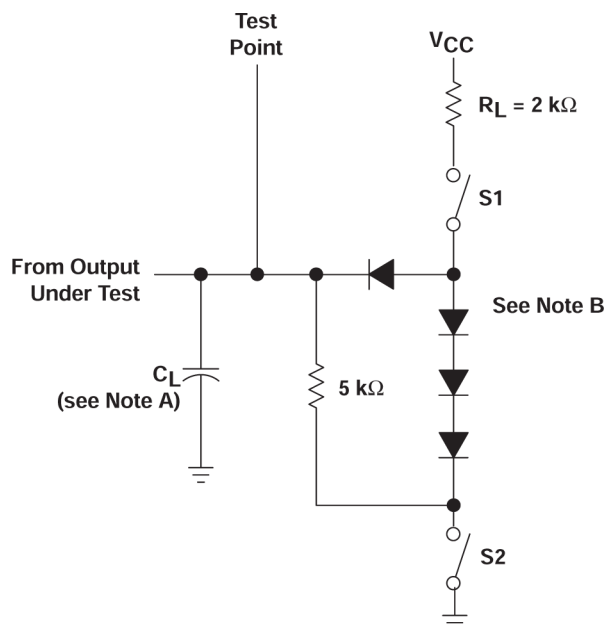
TEST CIRCUIT



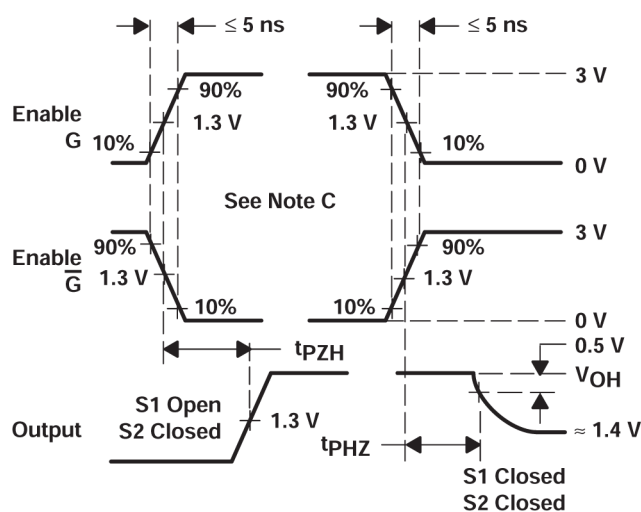
VOLTAGE WAVEFORMS

- The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1 \text{ MHz}$, duty cycle $\leq 50\%$, $Z_O = 50 \Omega$, $t_r \leq 6 \text{ ns}$, $t_f \leq 6 \text{ ns}$.
- C_L includes probe and jig capacitance.

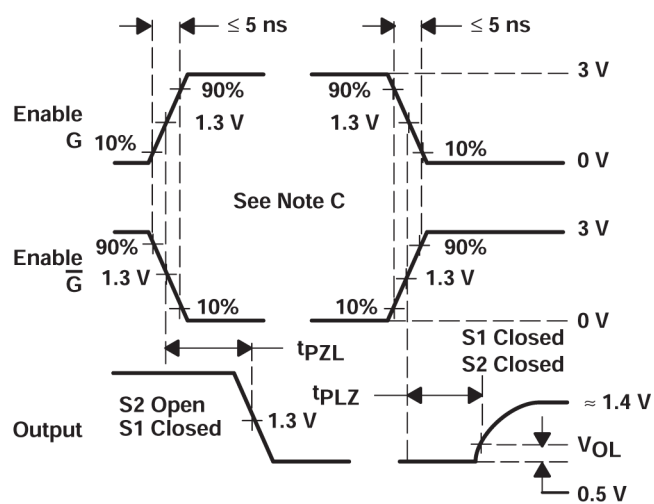
图 6-2. Test Circuit and Voltage Waveforms



LOAD CIRCUIT



VOLTAGE WAVEFORMS FOR t_{PHZ} , t_{PZH}



VOLTAGE WAVEFORMS FOR t_{PLZ} , t_{PZL}

- A. C_L includes probe and jig capacitance.
- B. All diodes are 1N3064 or equivalent.
- C. Enable G is tested with $\overline{G}$ high; $\overline{G}$ is tested with G low.

图 6-3. Load Circuit and Voltage Waveforms

7 Detailed Description
7.1 Device Functional Modes

表 7-1. Function Table (Each Receiver)

DIFFERENTIAL INPUTS A - B ⁽¹⁾	ENABLES		OUTPUT Y
	G	$\overline{G}$	
$V_{ID} \geq 0.2\text{ V}$	H	X	H
	X	L	H
$-0.2\text{ V}_{ID} < V_{ID} < 0.2\text{ V}$	H	X	?
	X	L	?
$V_{ID} \leq -0.2\text{ V}$	H	X	L
	X	L	L
X	L	H	Z
Open	H	X	H
	X	L	H

(1) H = high level, L = low level, X = irrelevant, ? = indeterminate, Z = high impedance (off)

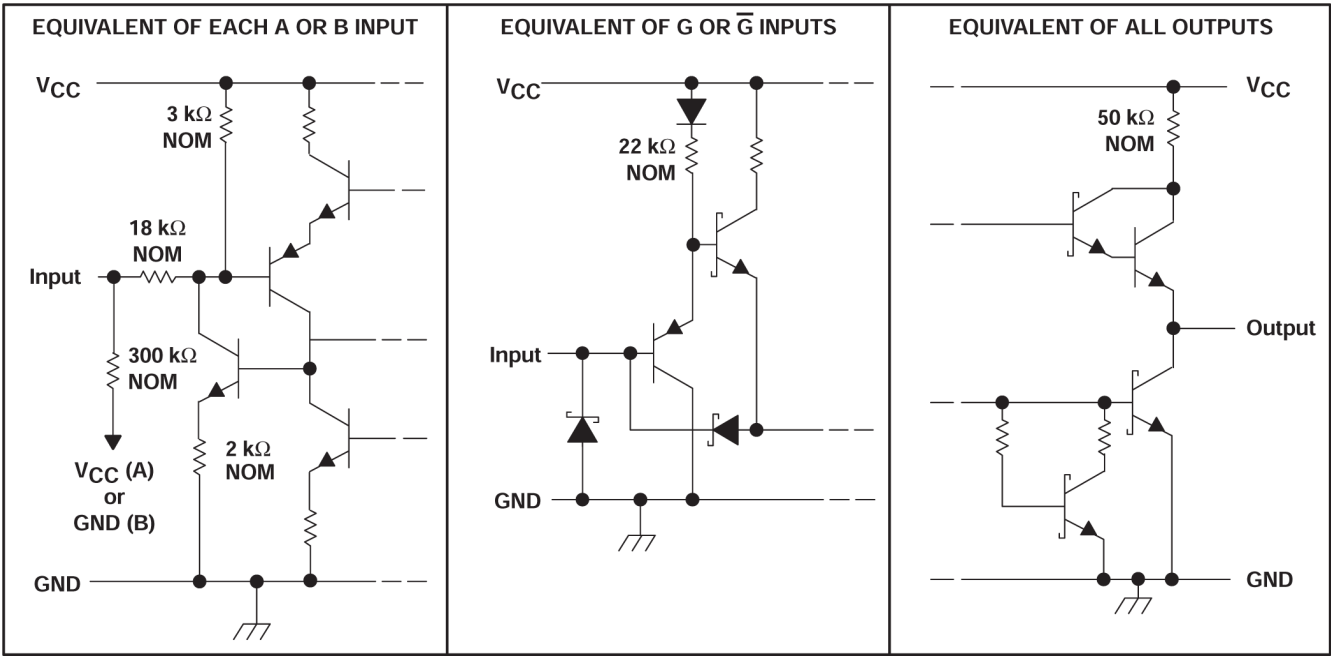


图 7-1. Schematics of Inputs and Outputs

8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

8.2 支持资源

[TI E2E™ 支持论坛](#) 是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《[使用条款](#)》。

8.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.
所有商标均为其各自所有者的财产。

8.4 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

8.5 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

9 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision D (May 1995) to Revision E (October 2023)	Page
• 更改了整个文档中的表格、图和交叉参考的编号格式.....	1

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN75ALS193D	LIFEBUY	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75ALS193	
SN75ALS193DR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75ALS193	Samples
SN75ALS193N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	(SN75ALS193N, SN7A LS193N)	Samples
SN75ALS193NE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	(SN75ALS193N, SN7A LS193N)	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75ALS193DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75ALS193DR	SOIC	D	16	2500	353.0	353.0	32.0

TUBE

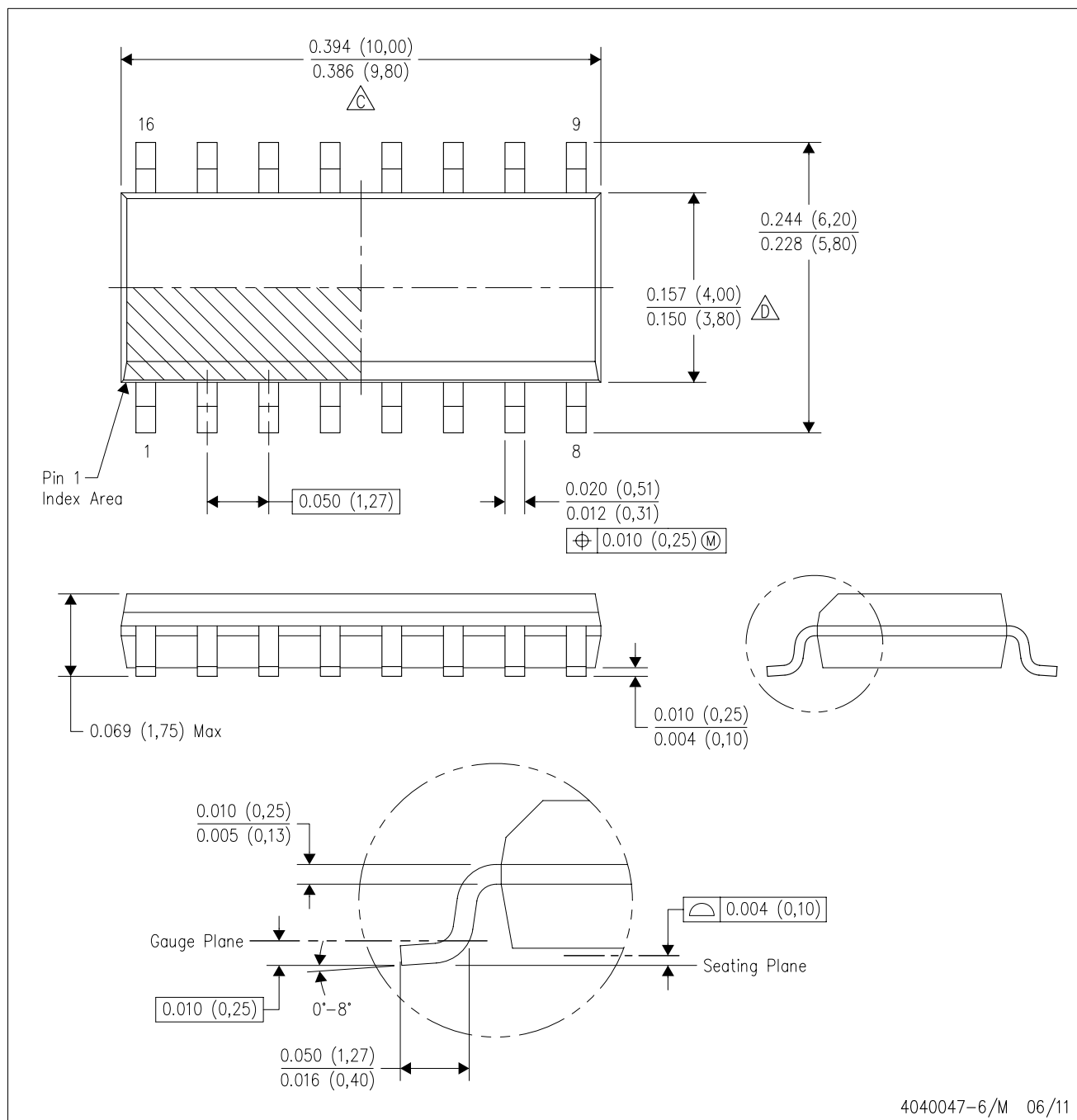


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN75ALS193D	D	SOIC	16	40	507	8	3940	4.32
SN75ALS193N	N	PDIP	16	25	506	13.97	11230	4.32
SN75ALS193NE4	N	PDIP	16	25	506	13.97	11230	4.32

D (R-PDSO-G16)

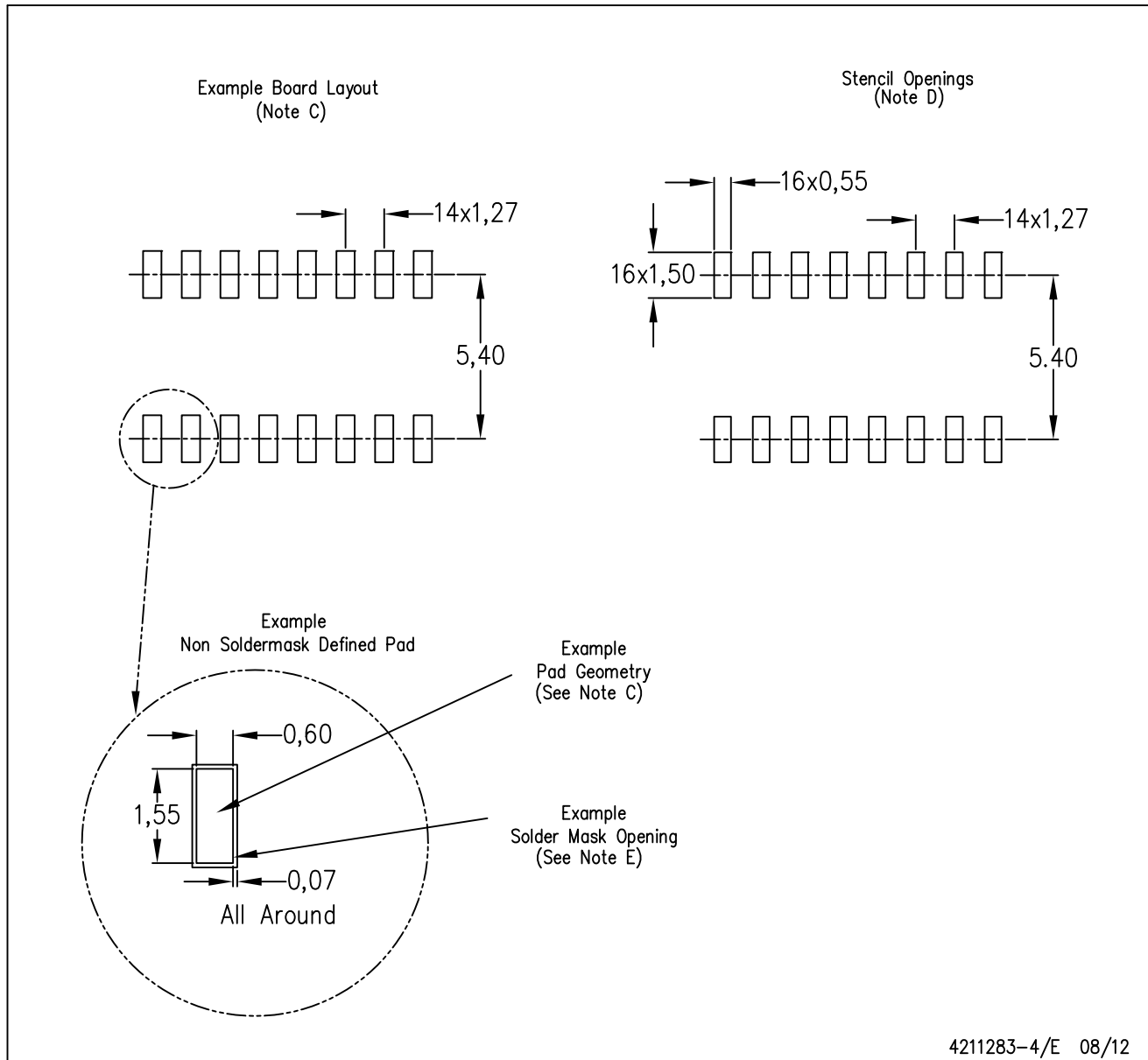
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



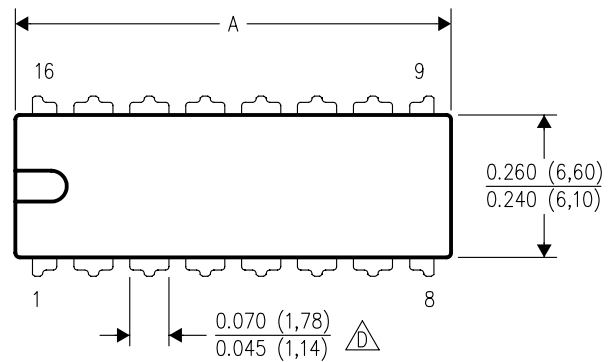
4211283-4/E 08/12

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

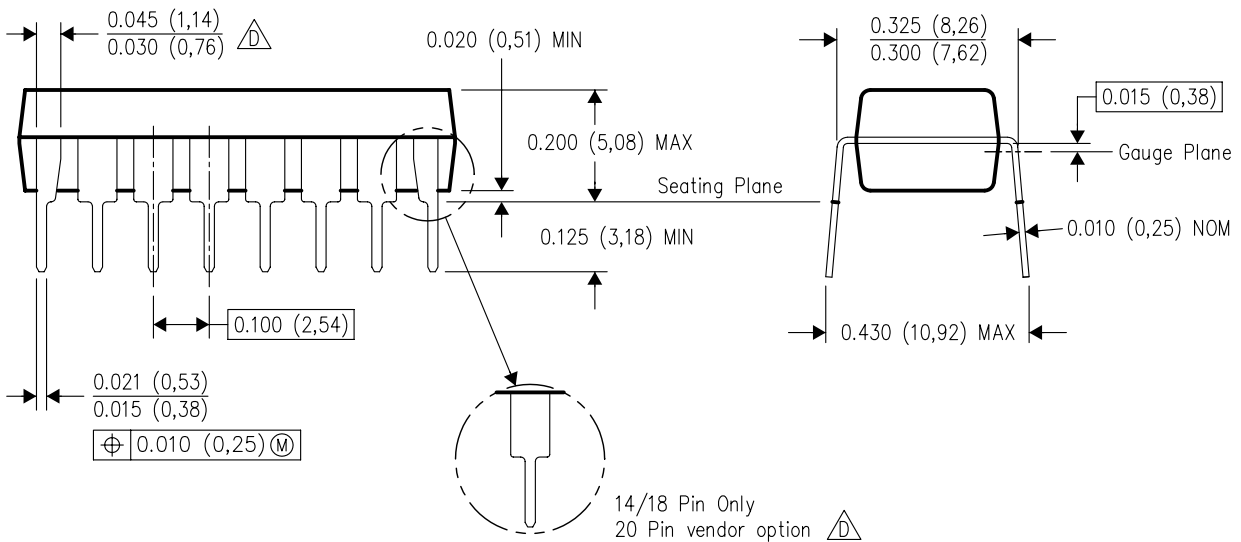
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS **	14	16	18	20
DIM				
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



14/18 Pin Only
20 Pin vendor option

4040049/E 12/2002

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 - The 20 pin end lead shoulder width is a vendor option, either half or full width.

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